In the Claims:

This listing of claim replaces all prior versions, and listings, of claims in the application:

- 1. (Currently Amended) An electroluminescent display device comprising:
- a plurality of pixels;
- a pixel selecting transistor provided for each of the pixels;
- an electroluminescent element provided for each of the pixels; and
- a driving transistor provided for each of the pixels to drive a corresponding electroluminescent element according to a display signal supplied through a corresponding pixel selecting transistor, the driving transistor comprising a channel of a P type and <u>being of</u> a lightly-doped-drain structure type.
- 2. (Original) The electroluminescent display device of claim 1, wherein the driving transistor further comprises a gate electrode, a P-type impurity region and a region of no doped impurities that is disposed between the gate electrode and the P-type impurity region.
- 3. (Currently Amended) The electroluminescent display device of claim 1, wherein the driving transistor further comprises a high concentration region containing a P-type impurity with a concentration of 1×10^{20} /cc or more and being in contact with an electrode, and a low concentration region containing a P-type impurity with a concentration of 1×10^{18} /cc or less and disposed between the high concentration region and the channel of the P type.
- 4. (Currently Amended) The electroluminescent display device of claim 2, wherein the P-type impurity region comprises a high concentration region containing a P-type impurity with a concentration of 1×10^{20} /cc or more and being in contact with an electrode, and a low concentration region containing a P-type impurity with a concentration of 1×10^{18} /cc or less and disposed between the high concentration region and the channel of the P type.
- 5. (Currently Amended) The electroluminescent display [[deice]] <u>device</u> of claim 1, further comprising a glass substrate on which the pixels, the pixel selecting transistors, the electroluminescent elements and the driving transistors are disposed.